# HAMAMATSU

PHOTON IS OUR BUSINESS

# PHOTOMULTIPLIER TUBES R7447 R7447P (For Photon Counting)

## FEATURES

| Spectral response         | 160 nm to 710 nm          |
|---------------------------|---------------------------|
| High cathode sensitivity  |                           |
| Luminous                  | 100 µA/Im                 |
| Radiant at 410 nm         |                           |
| High anode sensitivity    |                           |
| Luminous                  | 1200 A/Im                 |
| Radiant at 410 nm         | 8.4 × 10 <sup>5</sup> A/W |
| ●Low dark current         | 0.2 nA                    |
| ●Low dark counts (R7447P) | 10 s <sup>-1</sup>        |

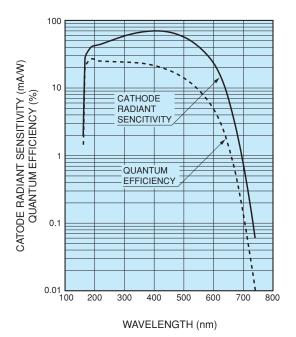


Environmental monitoring
Atomic emission spectrometer
Atomic absorption spectrometer

#### **SPECIFICATIONS** GENERAL Parameter **Description / Value** Unit Spectral response 160 to 710 nm Wavelength of maximum response 410 nm Low noise bialkali Material Photocathode Minimum effective area 8 × 24 mm Window material Silica Circular-cage Structure Dynode Number of stages 9 Direct Anode to last dynode 4 pF interelectrode Anode to all other 6 pF capacitances electrode Base 11-pin base Weight Approx. 45 g Operating ambient temperature -30 to +50 °C Storage temperature -30 to +50 °C Suitable socket E678-11A (sold separately) Suitable socket assembly E717-63 (sold separately)



### Figure 1: Typical spectral response



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## PHOTOMULTIPLIER TUBES R7447, R7447P (For Photon Counting)

#### MAXIMUM RATINGS (Absolute maximum values)

|                                      | Parameter                     | Value | Unit |
|--------------------------------------|-------------------------------|-------|------|
|                                      | Between anode and cathode     | 1250  | V    |
| Supply voltage                       | Between anode and last dynode | 250   | V    |
| Average anode current <sup>(A)</sup> |                               | 0.1   | mA   |

### CHARACTERISTICS (at 25 °C)

|                                | Parameter  | for g | R7447<br>eneral pur     | pose | for p | Unit                    |      |                 |
|--------------------------------|--|-------|-------------------------|------|-------|-------------------------|------|-----------------|
|                                |  | Min.  | Тур.                    | Max. | Min.  | Тур.                    | Max. |                 |
|                                | Quantum efficiency at 300 nm                                   | —     | 24                      | —    |       | 24                      | —    | %               |
| Cathode                        | Luminous <sup>®</sup>  | 80    | 100                     | —    | 80    | 100                     | —    | µA/lm           |
| sensitivity                    | Radiant at 410 nm (peak)                                       | —     | 70                      | —    | —     | 70                      | —    | mA/W            |
|                                | Blue sensitivity index ©                                       |       | 8                       | _    |       | 8                       | _    | —               |
| Anode                          | Anode Luminous <sup>(D)</sup><br>sensitivity Radiant at 410 nm |       | 1200                    | —    | 1000  | 1200                    | —    | A/Im            |
|                                |  |       | $8.4 \times 10^{5}$     | —    |       | 8.4 × 10 <sup>5</sup>   | —    | A/W             |
| Gain D                         |  |       | $1.2 \times 10^{7}$     | —    |       | $1.2 \times 10^{7}$     | —    | —               |
| Anode dark cur                 | rent (After 30 min storage in the darkness $^{(E)}$ )          |       | 0.2                     | 2.0  |       | 0.2                     | 0.5  | nA              |
| Anode dark counts ®            |  |       | —                       | _    |       | 10                      | 50   | S <sup>-1</sup> |
| ENI (Equivalent Noise Input) © |  |       | 3.3 × 10 <sup>-17</sup> | _    |       | 3.3 × 10 <sup>-17</sup> | _    | W               |
| Timo                           | Anode pulse rise time ®  |       | 2.2                     |      |       | 2.2                     |      | ns              |
| l ime –                        | Electron transit time ①  |       | 22                      |      |       | 22                      |      | ns              |
| response <sup>©</sup>          | Transit time spread (TTS) <sup>①</sup>                         |       | 1.2                     | —    |       | 1.2                     | —    | ns              |

### NOTES

- Averaged over any interval of 30 seconds maximum.
- B The light source is a tungsten filament lamp operated at a distribution temperature of 2856 kelvin. Supply voltage is 100 volts between the cathode and all other electrodes connected together as anode.
- © The value is cathode output current when a blue filter is interposed between the light source and the tube under the same condition as Note (B).
- D Measured with the same light source as Note B and with the voltage distribution ratio shown in Table 1 below.

#### Table 1: Voltage distribution ratio

| Electrodes         | ŀ | < | Dy | Dy1 Dy2 |  | Dy | 3 | Dy4 | Dy5 |  | Dy6 |   | Dy7 |   | Dy8 |   | Dy9 |   | Р |  |
|--------------------|---|---|----|---------|--|----|---|-----|-----|--|-----|---|-----|---|-----|---|-----|---|---|--|
| Distribution ratio |   | 1 |    |         |  | 1  | 1 |     | 1   |  | 1   | 1 |     | 1 |     | 1 |     | 1 |   |  |

Supply voltage: 1000 V, K: Cathode, Dy: Dynode, P: Anode © Measured with the same supply voltage and voltage distribution ratio

shown in Table 1.

©Measured at the plateau voltage.

#### Table 2: Voltage distribution ratio for plateau test

| Electrodes         | К | D | Dy1 |   | 2 D | Dy3 |  | /4 | Dy5 |  | Dy6 | Dy7 |  | Dy8 |  | Dy9 |  | Р |  |
|--------------------|---|---|-----|---|-----|-----|--|----|-----|--|-----|-----|--|-----|--|-----|--|---|--|
| Distribution ratio |   | 1 |     | 1 | 1   | 1   |  | 1  | 1   |  | 1   | 1   |  | 1   |  | 2   |  | 1 |  |

Supply voltage: Plateau voltage, K: Cathode, Dy: Dynode, P: Anode

© ENI is an indication of the photon-limited signal-to-noise ratio. It refers to the amount of light in watts to produce a signal-to-noise ratio of unity in the output of a photomultiplier tube.

$$ENI = \frac{\sqrt{2 \cdot q \cdot ldb \cdot G \cdot \Delta f}}{S} \quad (W)$$

where  $q = Electronic charge (1.60 \times 10^{-19} coulomb).$ 

- Idb = Anode dark current(after 30 minute storage) in amperes. G = Gain.
  - $\Delta f$  = Bandwidth of the system in hertz. 1 hertz is used.
  - S = Anode radiant sensitivity in amperes per watt at the wavelength of peak response.
- (H) The rise time is the time for the output pulse to rise from 10 % to 90 % of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
- ① The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitude. In measurement, the whole photocathode is illuminated.
- ③Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the signal photoelectron mode, and may be defined as the FWHM of the frequency distribution of electron transit times.



Figure 2: Typical gain and anode dark current

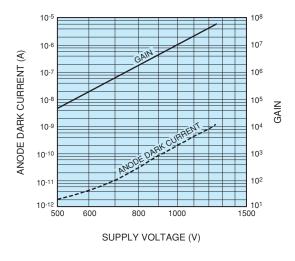
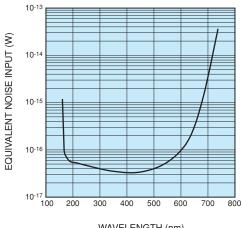
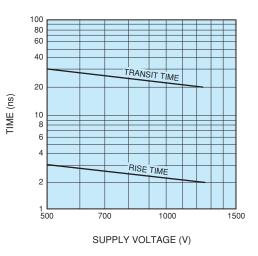


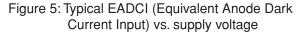
Figure 4: Typical ENI vs. wavelength

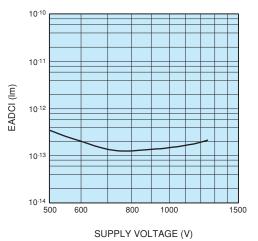


WAVELENGTH (nm)

Figure 3: Typical time response







Data shown here, which is given from a relation among supply voltage, anode sensitivity and dark current, serves as a good reference in order to determine the most suitable supply voltage or its range.

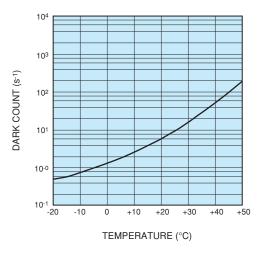
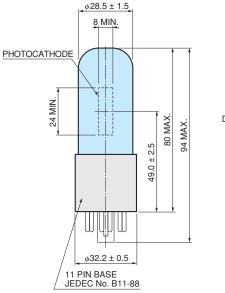
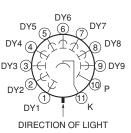


Figure 6: Typical temperature characteristics of dark count for R7447P

## **PHOTOMULTIPLIER TUBES** R7447, R7447P (For Photon Counting)

Figure 7: Dimensional outline and basing diagram(Unit: mm)





**BOTTOM VIEW** (BASING DIAGRAM) Figure 8: Socket (Unit: mm) | Sold separately |

E678-11A

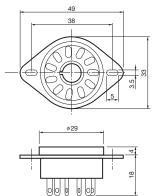
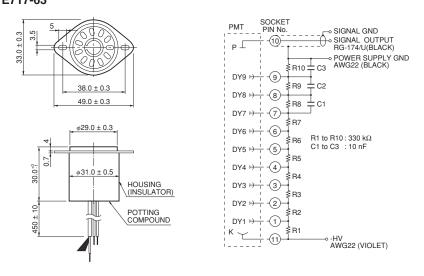


Figure 9: D-type socket assembly (Unit: mm) | Sold separately E717-63



\* Hamamatsu also provides C13890 series compact high voltage power supplies and C12597-01, C8991 DP type socket assemblies which incorporate a DC to DC converter type high voltage power supply.

### Warning-Personal Safety Hazards

Electrical Shock-Operating voltages applied to this device present a shock hazard.

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